

**Amendments to the Claims:**

This listing of claims will replace all prior versions, and listings, of claims in the applications:

**Listing of Claims:**

1. (Original) A method for providing field programmable platform array units, comprising:

cutting N by M array of platform array units from a field programmable platform array wafer according to an order from a customer, N and M being positive integers, said field programmable platform array wafer having all silicon layers and metal layers already built and including a plurality of platform array units, said plurality of platform array units being field programmable by a customer, each of said plurality of platform array units including at least one core and at least one processor, and interconnect between said plurality of platform array units being pre-routed on chip; and

packaging and testing said N by M array of platform array units.

2. (Original) The method of claim 1, further comprising:

programming said N by M array of platform array units by said customer.
3. (Original) The method of claim 2, wherein said programming is performed for at least one of unit specialization, unit role assignment, and inter-unit communications.
4. (Original) The method of claim 2, wherein said programming is performed with firmware.

5. (Original) The method of claim 1, wherein said N by M array of platform array units are within a single platform.
6. (Original) The method of claim 5, wherein said single platform is a storage area network (SAN) platform.
7. (Original) The method of claim 5, wherein said single platform is a digital signal processing (DSP) platform.
8. (Original) The method of claim 1, further comprising storing said field programmable platform array wafer.

9. (Original) A system for providing field programmable platform array units, comprising:

means for cutting N by M array of platform array units from a field programmable platform array wafer according to an order from a customer, N and M being positive integers, said field programmable platform array wafer having all silicon layers and metal layers already built and including a plurality of platform array units, said plurality of platform array units being field programmable by a customer, each of said plurality of platform array units including at least one core and at least one processor, and interconnect between said plurality of platform array units being pre-routed on chip; and

means for packaging and testing said N by M array of platform array units.

10. (Original) The system of claim 9, further comprising:

means for programming said N by M array of platform array units by said customer.

11. (Original) The system of claim 10, wherein said programming is performed for at least one of unit specialization, unit role assignment, and inter-unit communications.

12. (Original) The system of claim 10, wherein said programming is performed with firmware.

13. (Original) The system of claim 9, wherein said N by M array of platform array units are within a single platform.

14. (Original) The system of claim 13, wherein said single platform is a storage area network (SAN) platform.

15. (Original) The system of claim 13, wherein said single platform is a digital signal processing (DSP) platform.
16. (Original) The system of claim 9, further comprising means for storing said field programmable platform array wafer.

17. (Original) A semiconductor device, comprising:
- a plurality of platform array units being field programmable by a customer, each of said plurality of platform array units including at least one core and at least one processor;
- wherein interconnect between said plurality of platform array units being pre-routed.
18. (Currently Amended) The semiconductor device of claim 17, wherein said semiconductor device includes top aluminum pads and said top aluminum pads of said semiconductor device are used as a routing layer for the pre-routed interconnect between said plurality of platform array units.
19. (Original) The semiconductor device of claim 18, wherein encapsulation of lower copper metal layers of said semiconductor device is preserved by a standard die seal.
20. (Currently Amended) The semiconductor device of claim 17, wherein metal bumps of said semiconductor device are used as a routing layer for the pre-routed interconnect between said plurality of platform array units.
21. (Currently Amended) The semiconductor device of claim 17, wherein a copper layer within said semiconductor device is used as a routing layer for the pre-routed interconnect between said plurality of platform array units.
22. (Currently Amended) The semiconductor device of claim 17, wherein a polysilicon layer of said semiconductor device is used as a routing layer for the pre-routed interconnect between said plurality of platform array units.
23. (Currently Amended) The semiconductor device of claim 17, wherein a

silicon layer of said semiconductor device is used as a routing layer for the pre-routed interconnect between said plurality of platform array units.

24. (Original) The semiconductor device of claim 17, wherein said plurality of platform array units are configured by external software programming.